PALM INTRANET

Day: Tuesday Date: 6/22/2004

Time: 14:58:40

## **Inventor Name Search Result**

Your Search was:

Last Name = JUNG

First Name = TAE-SUNG

7					
Application#	Patent#	Status	Date Filed	Title	Inventor Name 27
10278486	Not Issued	030	10/23/2002	METHOD FOR TRANSMITTING DATA FROM SERVER OF VIRTUAL PRIVATE NETWORK TO MOBILE NODE	JUNG, TAE-SUNG
10246744	6603686	150	09/19/2002	SEMICONDUCTOR MEMORY DEVICE HAVING DIFFERENT DATA RATES IN READ OPERATION AND WRITE OPERATION	JUNG, TAE-SUNG
10187700	Not Issued	030	07/02/2002	METHOD OF TRANSMITTING DATA FROM SERVER OF VIRTUAL PRIVATE NETWORK TO MOBILE NODE	JUNG, TAE-SUNG
10035466	Not Issued	030	10/26/2001	HANDOVER METHOD FOR MOBILE STATION HAVING MOBILE IP ADDRESS IN MOBILE COMMUNICATION SYSTEM	JUNG, TAE-SUNG
10002534	Not Issued	030	11/01/2001	SYSTEM AND METHOD FOR ASSIGNING A MOBILE IP TO A MOBILE NODE	JUNG, TAE-SUNG
09990567	Not Issued	030	11/21/2001	REGIONAL TUNNEL MANAGEMENT METHOD IN A MOBILE COMMUNICATION SYSTEM USING MOBILE IP	JUNG, TAE-SUNG
09941091	Not Issued	030	,	INTEGRATED CIRCUIT MEMORY SYSTEMS HAVING PROGRAMMABLE SIGNAL BUFFERS FOR ADJUSTING SIGNAL TRANSMISSION DELAYS AND METHODS OF OPERATING SAME	JUNG, TAE-SUNG
09930973	<u>6477110</u>	150		SEMICONDUCTOR MEMORY DEVICE HAVING DIFFERENT	JUNG, TAE-SUNG

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				DATA RATES IN READ OPERATION AND WRITE OPERATION	
09918095	Not Issued	030	07/30/2001	PACKET TRANSMISSION METHOD FOR MOBILE INTERNET	JUNG, TAE-SUNG
09886552	6442057	150	06/21/2001	MEMORY MODULE FOR PREVENTING SKEW BETWEEN BUS LINES	JUNG, TAE-SUNG
09851277	Not Issued	041	05/08/2001	MEMORY INTERFACE SYSTEMS THAT COUPLE A MEMORY TO A MEMORY CONTROLLER AND ARE RESPONSIVE TO A TERMINAL VOLTAGE THAT IS INDEPENDENT OF SUPPLY VOLTAGES FOR THE MEMORY AND THE MEMORY CONTROLLER	JUNG, TAE-SUNG
09845550	6585525	150	04/30/2001	MEMORY MODULES HAVING CONDUCTORS AT EDGES THEREOF AND CONFIGURED TO CONDUCT SIGNALS TO OR FROM THE MEMEORY MODULES VIA THE RESPECTIVE EDGES	JUNG, TAE-SUNG
09514763	6275100	150	02/28/2000	REFERENCE VOLTAGE GENERATORS INCLUDING FIRST AND SECOND TRANSISTORS OF SAME CONDUCTIVITY TYPE AND AT LEAST ONE SWITCH	JUNG, TAE-SUNG
09082297	6044017	150	05/19/1998	NONVOLATILE MEMORY DEVICE HAVING FLASH EEPROM CELLS	JUNG, TAE-SUNG
08990023	5963475	150	12/12/1997	ADVANCED NONVOLATILE MEMORIES ADAPTABLE TO DYNAMIC RANDOM ACCESS MEMORIES AND METHODS OF OPERATING THEREIN	JUNG , TAE-SUNG
08927606	6040735	150	09/12/1997	REFERENCE VOLTAGE GENERATORS INCLUDING FIRST AND SECOND TRANSISTORS OF SAME CONDUCTIVITY TYPE	JUNG , TAE-SUNG
08769588	6012122	150		SYSTEMS AND METHODS FOR DISTINGUISHING BETWEEN	JUNG , TAE-SUNG

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				MEMORY TYPES	
08739276	5732018	150	10/29/1996	SELF-CONTAINED REPROGRAMMING NONVOLATILE INTEGRATED CIRCUIT MEMORY DEVICES AND METHODS	JUNG , TAE-SUNG
08716022	5677873	150	09/19/1996	METHODS OF PROGRAMMING FLASH EEPROM INTEGRATED CIRCUIT MEMORY DEVICES TO PREVENT INADVERTENT PROGRAMMING OF NONDESIGNATED NAND MEMORY CELLS THEREIN	JUNG , TAE-SUNG
08686423	5771192	150	07/26/1996	BIT LINE REFERENCE CIRCUIT FOR A NONVOLATILE SEMICONDUCTOR MEMORY DEVICE	JUNG , TAE-SUNG
08663350	5761123	150	06/13/1996	SENSE AMPLIFIER CIRCUIT OF A NONVOLATILE SEMICONDUCTOR MEMORY DEVICE	JUNG , TAE-SUNG
08650399	5796273	150	05/20/1996	SENSE AMPLIFIER FOR SEMICONDUCTOR MEMORY DEVICE	JUNG , TAE-SUNG
08638100	5737258	150	04/26/1996	NONVOLATILE SEMICONDUCTOR MEMORY WHICH IS CONNECTABLE TO A DRAM BUS	JUNG , TAE-SUNG
08623793	5621684	150		A NONVOLATILE SEMICONDUCTOR MEMORY WITH DIFFERENT PASS POTENTIAL APPLIED TO THE FIRST TWO ADJACENT WORD LINES	JUNG , TAE-SUNG
07292449	4964084	150	11 1	STATIC RANDOM ACCESS MEMORY DEVICE WITH VOLTAGE CONTROL CIRCUIT	JUNG , TAE-SUNG
07289731	4890051	150	12/27/1988	CMOS INPUT BUFFER STABLE FOR THE VARIATION OF A POWER SUPPLYING VOLTAGE	JUNG , TAE-SUNG
07238247	5067109	150	08/30/1988	A DATA OUTPUT BUFFER CIRCUIT FOR A SRAM	JUNG , TAE-SUNG

Inventor Search Completed: No Records to Display.

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